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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

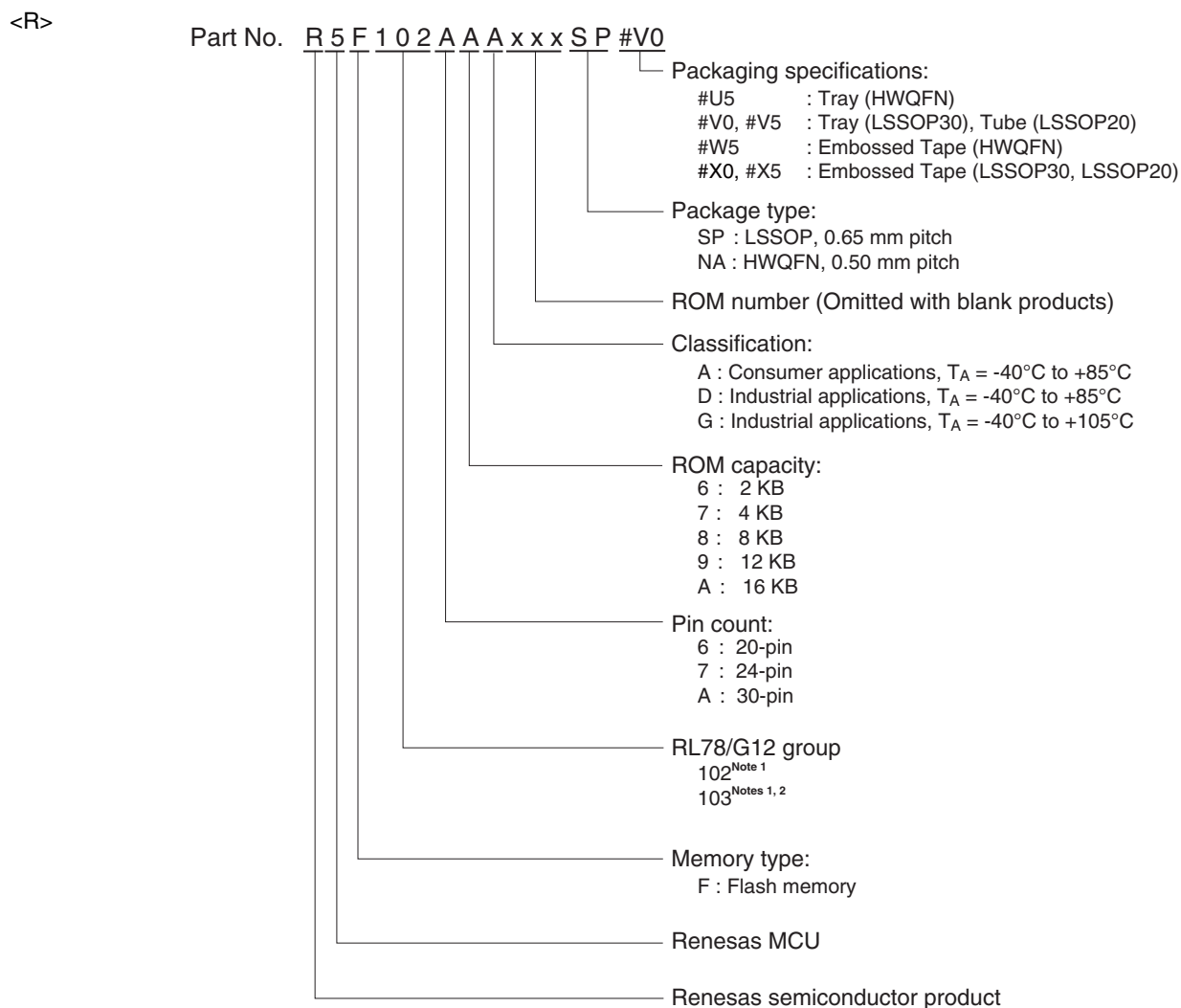
### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	24MHz
Connectivity	CSI, I <sup>2</sup> C, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	14
Program Memory Size	4KB (4K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	512 x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 11x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	20-LSSOP (0.173", 4.40mm Width)
Supplier Device Package	20-LSSOP
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10267asp-v5">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10267asp-v5</a>

## 1.2 List of Part Numbers

Figure 1-1. Part Number, Memory Size, and Package of RL78/G12



- Notes**
- For details about the differences between the R5F102 products and the R5F103 products of RL78/G12, see **1.1 Differences between the R5F102 Products and the R5F103 Products**.
  - Products only for "A: Consumer applications ( $T_A = -40$  to  $+85^{\circ}\text{C}$ )" and "D: Industrial applications ( $T_A = -40$  to  $+85^{\circ}\text{C}$ )"

## (2) 30-pin products

(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

(1/2)

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current <small>Note 1</small>	I <sub>DD1</sub>	Operating mode	HS (High-speed main) mode <small>Note 4</small>	f <sub>IH</sub> = 24 MHz <small>Note 3</small>	Basic operation	V <sub>DD</sub> = 5.0 V		1.5		mA
						V <sub>DD</sub> = 3.0 V		1.5		
					Normal operation	V <sub>DD</sub> = 5.0 V		3.7	5.5	mA
						V <sub>DD</sub> = 3.0 V		3.7	5.5	
				f <sub>IH</sub> = 16 MHz <small>Note 3</small>		V <sub>DD</sub> = 5.0 V		2.7	4.0	mA
						V <sub>DD</sub> = 3.0 V		2.7	4.0	
						V <sub>DD</sub> = 3.0 V		1.2	1.8	mA
						V <sub>DD</sub> = 2.0 V		1.2	1.8	
			HS (High-speed main) mode <small>Note 4</small>	f <sub>MX</sub> = 20 MHz <small>Note 2</small> , V <sub>DD</sub> = 5.0 V		Square wave input		3.0	4.6	mA
						Resonator connection		3.2	4.8	
						Square wave input		3.0	4.6	mA
						Resonator connection		3.2	4.8	
				f <sub>MX</sub> = 10 MHz <small>Note 2</small> , V <sub>DD</sub> = 5.0 V		Square wave input		1.9	2.7	mA
						Resonator connection		1.9	2.7	
						Square wave input		1.9	2.7	mA
						Resonator connection		1.9	2.7	
			LS (Low-speed main) mode <small>Note 4</small>	f <sub>MX</sub> = 8 MHz <small>Note 2</small> , V <sub>DD</sub> = 3.0 V		Square wave input		1.1	1.7	mA
						Resonator connection		1.1	1.7	
				f <sub>MX</sub> = 8 MHz <small>Note 2</small> , V <sub>DD</sub> = 2.0 V		Square wave input		1.1	1.7	mA
						Resonator connection		1.1	1.7	

**Notes** 1. Total current flowing into V<sub>DD</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub> or V<sub>SS</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

2. When high-speed on-chip oscillator clock is stopped.

3. When high-speed system clock is stopped

4. Relationship between operation voltage width, operation frequency of CPU and operation mode is as follows.

HS(High speed main) mode: V<sub>DD</sub> = 2.7 V to 5.5 V @ 1 MHz to 24 MHz

V<sub>DD</sub> = 2.4 V to 5.5 V @ 1 MHz to 16 MHz

LS(Low speed main) mode: V<sub>DD</sub> = 1.8 V to 5.5 V @ 1 MHz to 8 MHz

**Remarks** 1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

2. f<sub>IH</sub>: high-speed on-chip oscillator clock frequency

3. Temperature condition of the TYP. value is T<sub>A</sub> = 25°C.

**(3) Peripheral functions (Common to all products)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed onchip oscillator operating current	$I_{FIL}$ <sup>Note 1</sup>				0.20		$\mu\text{A}$
12-bit interval timer operating current	$I_{TMKA}$ <sup>Notes 1, 2, 3</sup>				0.02		$\mu\text{A}$
Watchdog timer operating current	$I_{WDT}$ <sup>Notes 1, 2, 4</sup>	$f_{IL} = 15\text{ kHz}$			0.22		$\mu\text{A}$
A/D converter operating current	$I_{ADC}$ <sup>Notes 1, 5</sup>	When conversion at maximum speed	Normal mode, $AV_{REFP} = V_{DD} = 5.0\text{ V}$		1.30	1.70	mA
			Low voltage mode, $AV_{REFP} = V_{DD} = 3.0\text{ V}$		0.50	0.70	mA
A/D converter reference voltage operating current	$I_{ADREF}$ <sup>Note 1</sup>				75.0		$\mu\text{A}$
Temperature sensor operating current	$I_{TMPS}$ <sup>Note 1</sup>				75.0		$\mu\text{A}$
LVD operating current	$I_{LVD}$ <sup>Notes 1, 6</sup>				0.08		$\mu\text{A}$
Self-programming operating current	$I_{FSP}$ <sup>Notes 1, 8</sup>				2.00	12.20	mA
BGO operating current	$I_{BGO}$ <sup>Notes 1, 7</sup>				2.00	12.20	mA
SNOOZE operating current	$I_{SNOZ}$ <sup>Note 1</sup>	ADC operation	The mode is performed <sup>Note 9</sup>		0.50	0.60	mA
			The A/D conversion operations are performed, Low voltage mode, $AV_{REFP} = V_{DD} = 3.0\text{ V}$		1.20	1.44	mA
		CSI/UART operation			0.70	0.84	mA

**Notes** 1. Current flowing to the  $V_{DD}$ .

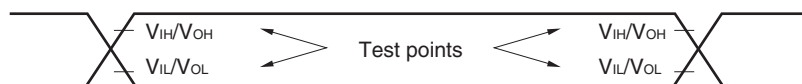
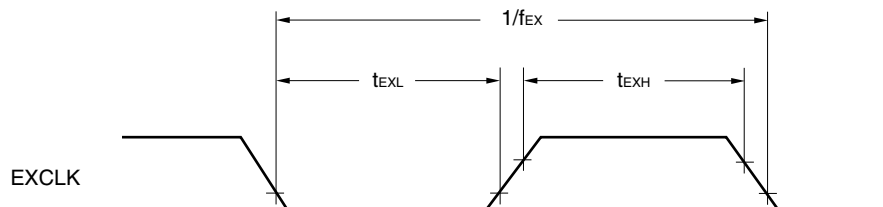
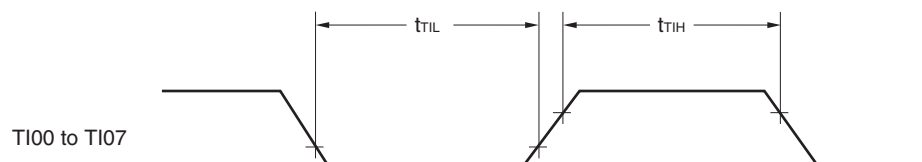
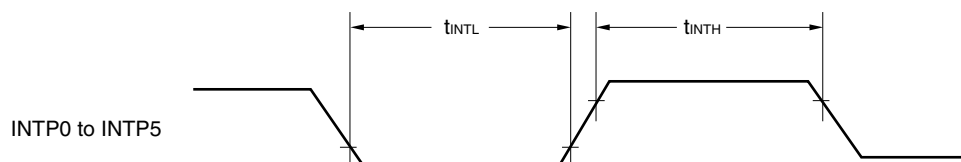
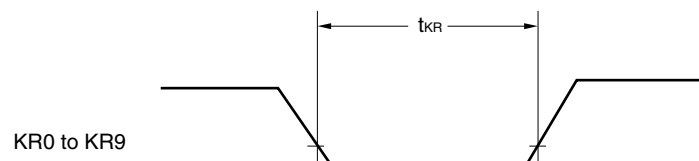
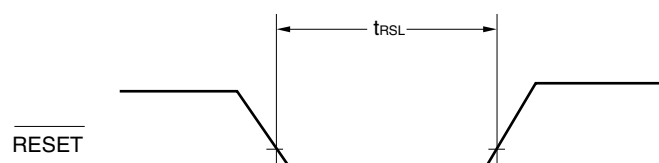
2. When high speed on-chip oscillator and high-speed system clock are stopped.

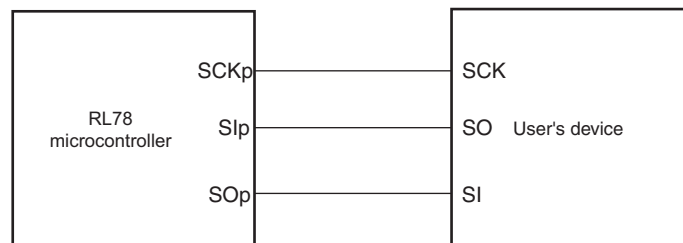
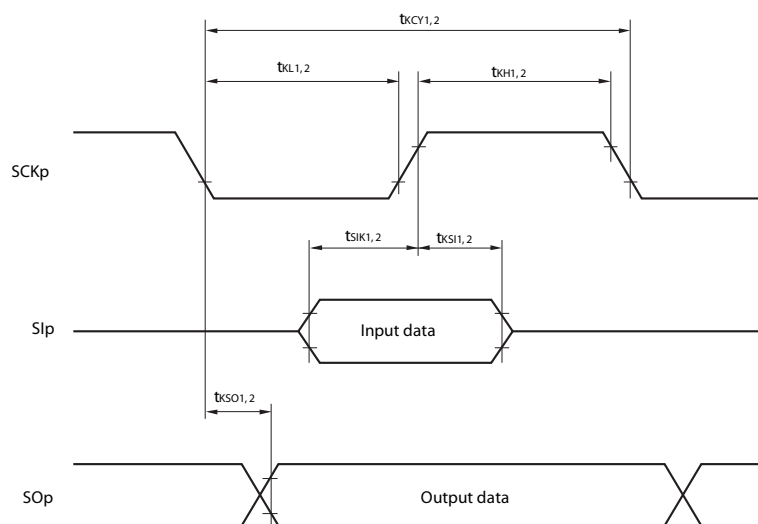
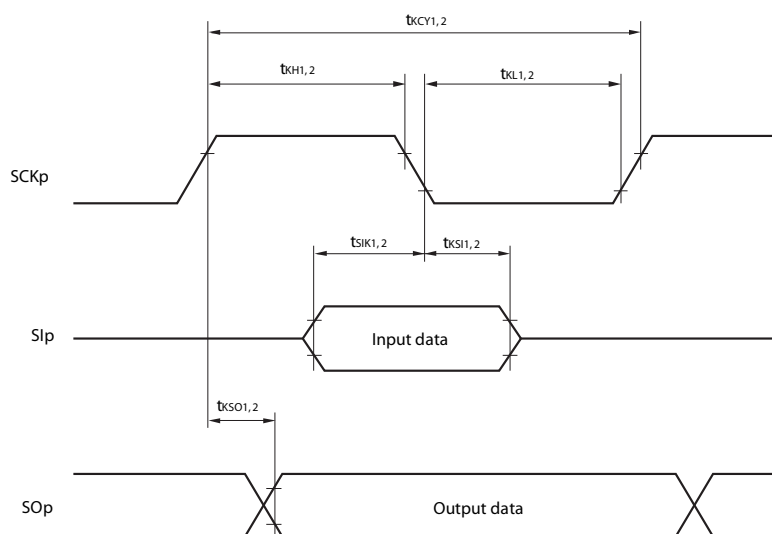
3. Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator). The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$ , and  $I_{FIL}$  and  $I_{TMKA}$  when the 12-bit interval timer operates.4. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{WDT}$  when the watchdog timer operates.5. Current flowing only to the A/D converter. The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$  or  $I_{DD2}$  and  $I_{ADC}$  when the A/D converter operates in an operation mode or the HALT mode.6. Current flowing only to the LVD circuit. The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{LVD}$  when the LVD circuit operates.

7. Current flowing only during data flash rewrite.

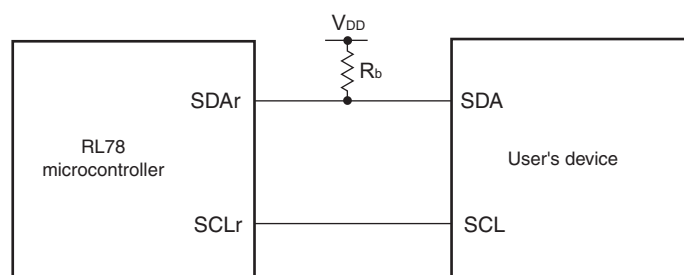
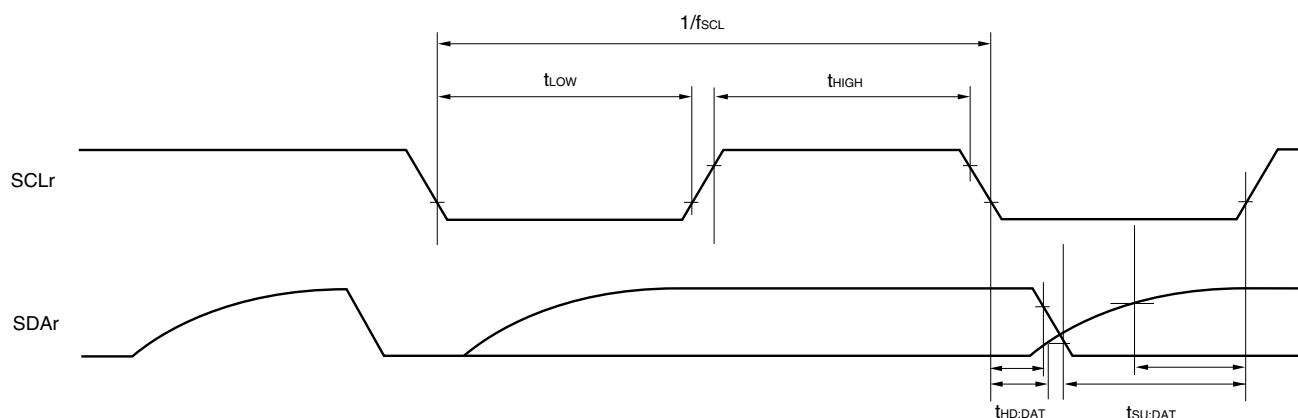
8. Current flowing only during self programming.

9. For shift time to the SNOOZE mode, see **17.3.3 SNOOZE mode**.**Remarks** 1.  $f_{IL}$ : Low-speed on-chip oscillator clock frequency2. Temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$

**AC Timing Test Point****External Main System Clock Timing****TI/TO Timing****Interrupt Request Input Timing****Key Interrupt Input Timing****RESET Input Timing**

**CSI mode connection diagram (during communication at same potential)**
**CSI mode serial transfer timing (during communication at same potential)**  
 (When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 0$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 1$ .)

**CSI mode serial transfer timing (during communication at same potential)**  
 (When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 1$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 0$ .)


(Remarks are listed on the next page.)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)**

- Remarks**
1.  $R_b$  [ $\Omega$ ]: Communication line (SDAr) pull-up resistance  
 $C_b$  [F]: Communication line (SCLr, SDAr) load capacitance
  2.  $r$ : IIC number ( $r = 00, 01, 11, 20$ ),  $h$ : = POM number ( $h = 0, 1, 4, 5$ )
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the serial clock select register  $m$  (SPSm) and the CKSmn bit of serial mode register  $mn$  (SMRmn).  $m$ : Unit number ( $m = 0, 1$ ),  $n$ : Channel number ( $0, 1, 3$ ))
  4. Simplified I<sup>2</sup>C mode is supported only by the R5F102 products.

5. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to **Note 4** above to calculate the maximum transfer rate under conditions of the customer.

6. The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ V<sub>DD</sub> < 4.0 V and 2.3 V ≤ V<sub>b</sub> ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \quad [\text{bps}]$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 [\%]$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

7. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to **Note 6** above to calculate the maximum transfer rate under conditions of the customer.

8. The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 1.8 V ≤ V<sub>DD</sub> < 3.3 V, 1.6 V ≤ V<sub>b</sub> ≤ 2.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \quad [\text{bps}]$$

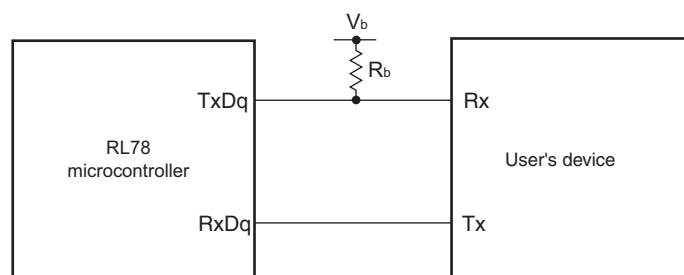
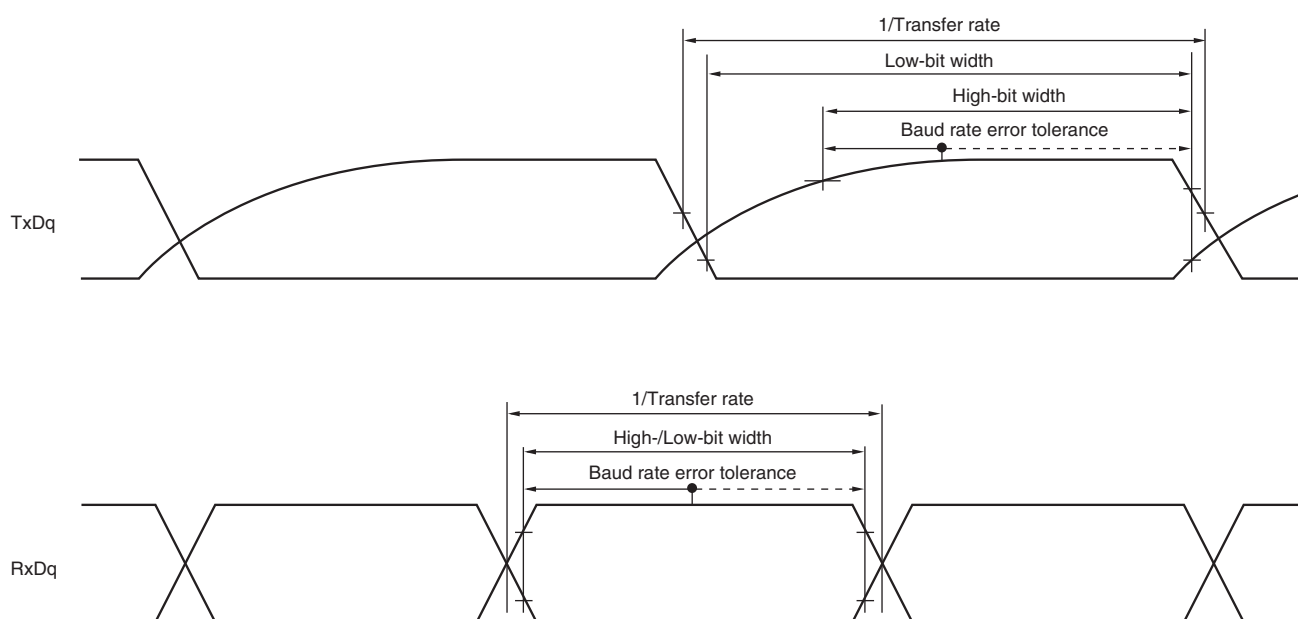
$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 [\%]$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

9. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to **Note 8** above to calculate the maximum transfer rate under conditions of the customer.

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V<sub>DD</sub> tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.



**UART mode connection diagram (during communication at different potential)****UART mode bit width (during communication at different potential) (reference)**

- Remarks**
1.  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  $C_b[F]$ : Communication line (TxDq) load capacitance,  $V_b[V]$ : Communication line voltage
  2. q: UART number (q = 0 to 2), g: PIM and POM number (g = 0, 1)
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn).  
m: Unit number, n: Channel number (mn = 00 to 03, 10, 11))
  4. UART0 of the 20- and 24-pin products supports communication at different potential only when the peripheral I/O redirection function is not used.

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (1/3)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	$t_{KCY1}$	$t_{KCY1} \geq 4/f_{CLK}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	300		1150		ns
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	500		1150		ns
			$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}^{\text{Note}}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	1150		1150		ns
SCKp high-level width	$t_{KH1}$		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	$t_{KCY1}/2 - 75$		$t_{KCY1}/2 - 75$		ns
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$t_{KCY1}/2 - 170$		$t_{KCY1}/2 - 170$		ns
			$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}^{\text{Note}}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$t_{KCY1}/2 - 458$		$t_{KCY1}/2 - 458$		ns
SCKp low-level width	$t_{KL1}$		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	$t_{KCY1}/2 - 12$		$t_{KCY1}/2 - 50$		ns
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$t_{KCY1}/2 - 18$		$t_{KCY1}/2 - 50$		ns
			$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}^{\text{Note}}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$t_{KCY1}/2 - 50$		$t_{KCY1}/2 - 50$		ns

**Note** Use it with  $V_{DD} \geq V_b$ .

**Cautions 1.** Select the TTL input buffer for the SIp pin and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SOp pin and SCKp pin by using port input mode register 1 (PIM1) and port output mode register 1 (POM1). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

**2.** CSI01 and CSI11 cannot communicate at different potential.

**Remarks 1.**  $R_b$  [ $\Omega$ ]: Communication line (SCKp, SOp) pull-up resistance,  $C_b$  [F]: Communication line (SCKp, SOp) load capacitance,  $V_b$  [V]: Communication line voltage

**2.** p: CSI number (p = 00, 20)

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (3/3)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

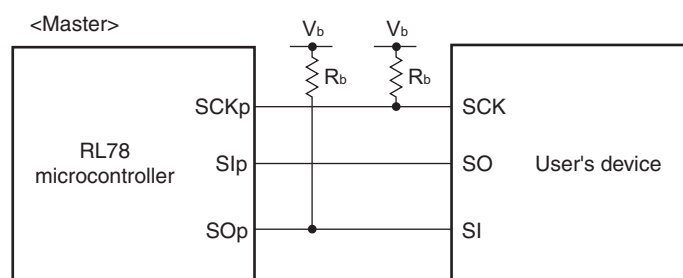
Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↓) <sup>Note 1</sup>	$t_{SIK1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	44		110		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	44		110		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	110		110		ns
Slp hold time (from SCKp↓) <sup>Note 1</sup>	$t_{KSI1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	19		19		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	19		19		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	19		19		ns
Delay time from SCKp↑ to SOp output <sup>Note 1</sup>	$t_{KSO1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$		25		25	ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		25		25	ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		25		25	ns

**Notes** 1. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.2. Use it with  $V_{DD} \geq V_b$ .**Cautions** 1. Select the TTL input buffer for the Slp pin and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SOp pin and SCKp pin by using port input mode register 1 (PIM1) and port output mode register 1 (POM1). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

2. CSI01 and CSI11 cannot communicate at different potential.

**Remarks** 1.  $R_b$  [ $\Omega$ ]: Communication line (SCKp, SOp) pull-up resistance,  $C_b$  [F]: Communication line (SCKp, SOp) load capacitance,  $V_b$  [V]: Communication line voltage

2. p: CSI number (p = 00, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0)

**CSI mode connection diagram (during communication at different potential)**

- Notes**
1. Excludes quantization error ( $\pm 1/2$  LSB).
  2. This value is indicated as a ratio (%FSR) to the full-scale value.
  3. When  $AV_{REFP} < V_{DD}$ , the MAX. values are as follows.  
 Overall error: Add  $\pm 1.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
 Zero-scale error/Full-scale error: Add  $\pm 0.05\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
 Integral linearity error/ Differential linearity error: Add  $\pm 0.5$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .
  4. Values when the conversion time is set to  $57\ \mu\text{s}$  (min.) and  $95\ \mu\text{s}$  (max.).
  5. Refer to **28.6.2 Temperature sensor/internal reference voltage characteristics**.

(2) When reference voltage (+) =  $AV_{REFP}/ANI0$  ( $ADREFP1 = 0$ ,  $ADREFP0 = 1$ ), reference voltage (–) =  $AV_{REFM}/ANI1$  ( $ADREFM = 1$ ), target pin: ANI16 to ANI22

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\ \text{V} \leq AV_{REFP} \leq V_{DD} \leq 5.5\ \text{V}$ ,  $V_{SS} = 0\ \text{V}$ , Reference voltage (+) =  $AV_{REFP}$ , Reference voltage (–) =  $AV_{REFM} = 0\ \text{V}$ )

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution $AV_{REFP} = V_{DD}$ <sup>Note 3</sup>			1.2	$\pm 5.0$	LSB
					1.2	$\pm 8.5$ <sup>Note 4</sup>	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target ANI pin: ANI16 to ANI22	$3.6\ \text{V} \leq V_{DD} \leq 5.5\ \text{V}$	2.125		39	$\mu\text{s}$
			$2.7\ \text{V} \leq V_{DD} \leq 5.5\ \text{V}$	3.1875		39	$\mu\text{s}$
			$1.8\ \text{V} \leq V_{DD} \leq 5.5\ \text{V}$	17		39	$\mu\text{s}$
				57		95	$\mu\text{s}$
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution $AV_{REFP} = V_{DD}$ <sup>Note 3</sup>				$\pm 0.35$	%FSR
						$\pm 0.60$ <sup>Note 4</sup>	%FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution $AV_{REFP} = V_{DD}$ <sup>Note 3</sup>				$\pm 0.35$	%FSR
						$\pm 0.60$ <sup>Note 4</sup>	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution $AV_{REFP} = V_{DD}$ <sup>Note 3</sup>				$\pm 3.5$	LSB
						$\pm 6.0$ <sup>Note 4</sup>	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution $AV_{REFP} = V_{DD}$ <sup>Note 3</sup>				$\pm 2.0$	LSB
						$\pm 2.5$ <sup>Note 4</sup>	LSB
Analog input voltage	V <sub>AIN</sub>	ANI16 to ANI22		0		$AV_{REFP}$ and $V_{DD}$	V

- Notes**
1. Excludes quantization error ( $\pm 1/2$  LSB).
  2. This value is indicated as a ratio (%FSR) to the full-scale value.
  3. When  $AV_{REFP} \leq V_{DD}$ , the MAX. values are as follows.  
 Overall error: Add  $\pm 4.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
 Zero-scale error/Full-scale error: Add  $\pm 0.20\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
 Integral linearity error/ Differential linearity error: Add  $\pm 2.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .
  4. When the conversion time is set to  $57\ \mu\text{s}$  (min.) and  $95\ \mu\text{s}$  (max.).

## 2.6.4 LVD circuit characteristics

**LVD Detection Voltage of Reset Mode and Interrupt Mode**(T<sub>A</sub> = -40 to +85°C, V<sub>PDR</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection supply voltage	V <sub>LVD0</sub>	Power supply rise time	3.98	4.06	4.14	V
		Power supply fall time	3.90	3.98	4.06	V
	V <sub>LVD1</sub>	Power supply rise time	3.68	3.75	3.82	V
		Power supply fall time	3.60	3.67	3.74	V
	V <sub>LVD2</sub>	Power supply rise time	3.07	3.13	3.19	V
		Power supply fall time	3.00	3.06	3.12	V
	V <sub>LVD3</sub>	Power supply rise time	2.96	3.02	3.08	V
		Power supply fall time	2.90	2.96	3.02	V
	V <sub>LVD4</sub>	Power supply rise time	2.86	2.92	2.97	V
		Power supply fall time	2.80	2.86	2.91	V
	V <sub>LVD5</sub>	Power supply rise time	2.76	2.81	2.87	V
		Power supply fall time	2.70	2.75	2.81	V
	V <sub>LVD6</sub>	Power supply rise time	2.66	2.71	2.76	V
		Power supply fall time	2.60	2.65	2.70	V
	V <sub>LVD7</sub>	Power supply rise time	2.56	2.61	2.66	V
		Power supply fall time	2.50	2.55	2.60	V
	V <sub>LVD8</sub>	Power supply rise time	2.45	2.50	2.55	V
		Power supply fall time	2.40	2.45	2.50	V
	V <sub>LVD9</sub>	Power supply rise time	2.05	2.09	2.13	V
		Power supply fall time	2.00	2.04	2.08	V
	V <sub>LVD10</sub>	Power supply rise time	1.94	1.98	2.02	V
		Power supply fall time	1.90	1.94	1.98	V
	V <sub>LVD11</sub>	Power supply rise time	1.84	1.88	1.91	V
		Power supply fall time	1.80	1.84	1.87	V
Minimum pulse width	t <sub>LW</sub>		300			μs
Detection delay time					300	μs

**LVD detection voltage of interrupt & reset mode****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{PDR} \leq V_{DD} \leq 5.5$  V,  $V_{SS} = 0$  V)**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Interrupt and reset mode	V <sub>LVD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 0, 1, falling reset voltage		1.80	1.84	1.87	V
	V <sub>LVD1</sub>	LVIS1, LVIS0 = 1, 0	Rising reset release voltage	1.94	1.98	2.02	V
			Falling interrupt voltage	1.90	1.94	1.98	V
	V <sub>LVD2</sub>	LVIS1, LVIS0 = 0, 1	Rising reset release voltage	2.05	2.09	2.13	V
			Falling interrupt voltage	2.00	2.04	2.08	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 0	Rising reset release voltage	3.07	3.13	3.19	V
			Falling interrupt voltage	3.00	3.06	3.12	V
	V <sub>LVD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 1, 0, falling reset voltage		2.40	2.45	2.50	V
	V <sub>LVD1</sub>	LVIS1, LVIS0 = 1, 0	Rising reset release voltage	2.56	2.61	2.66	V
			Falling interrupt voltage	2.50	2.55	2.60	V
	V <sub>LVD2</sub>	LVIS1, LVIS0 = 0, 1	Rising reset release voltage	2.66	2.71	2.76	V
			Falling interrupt voltage	2.60	2.65	2.70	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 0	Rising reset release voltage	3.68	3.75	3.82	V
			Falling interrupt voltage	3.60	3.67	3.74	V
	V <sub>LVD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 1, 1, falling reset voltage		2.70	2.75	2.81	V
	V <sub>LVD1</sub>	LVIS1, LVIS0 = 1, 0	Rising reset release voltage	2.86	2.92	2.97	V
			Falling interrupt voltage	2.80	2.86	2.91	V
	V <sub>LVD2</sub>	LVIS1, LVIS0 = 0, 1	Rising reset release voltage	2.96	3.02	3.08	V
			Falling interrupt voltage	2.90	2.96	3.02	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 0	Rising reset release voltage	3.98	4.06	4.14	V
			Falling interrupt voltage	3.90	3.98	4.06	V

**2.6.5 Power supply voltage rising slope characteristics****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{SS} = 0$  V)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	S <sub>VDD</sub>				54	V/ms

**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until  $V_{DD}$  reaches the operating voltage range shown in 28.4 AC Characteristics.

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )****(3/4)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage, high	$V_{IH1}$	Normal input buffer 20-, 24-pin products: P00 to P03 <sup>Note 2</sup> , P10 to P14, P40 to P42 30-pin products: P00, P01, P10 to P17, P30, P31, P40, P50, P51, P120, P147	$0.8V_{DD}$		$V_{DD}$	V
	$V_{IH2}$	TTL input buffer 20-, 24-pin products: P10, P11 30-pin products: P01, P10, P11, P13 to P17	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.2	$V_{DD}$	V
			$3.3\text{ V} \leq V_{DD} < 4.0\text{ V}$	2.0	$V_{DD}$	V
			$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$	1.5	$V_{DD}$	V
	$V_{IH3}$	Normal input buffer P20 to P23	$0.7V_{DD}$		$V_{DD}$	V
	$V_{IH4}$	P60, P61	$0.7V_{DD}$		6.0	V
	$V_{IH5}$	P121, P122, P125 <sup>Note 1</sup> , P137, EXCLK, RESET	$0.8V_{DD}$		$V_{DD}$	V
Input voltage, low	$V_{IL1}$	Normal input buffer 20-, 24-pin products: P00 to P03 <sup>Note 2</sup> , P10 to P14, P40 to P42 30-pin products: P00, P01, P10 to P17, P30, P31, P40, P50, P51, P120, P147	0		$0.2V_{DD}$	V
	$V_{IL2}$	TTL input buffer 20-, 24-pin products: P10, P11 30-pin products: P01, P10, P11, P13 to P17	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	0	0.8	V
			$3.3\text{ V} \leq V_{DD} < 4.0\text{ V}$	0	0.5	V
			$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$	0	0.32	V
	$V_{IL3}$	P20 to P23	0		$0.3V_{DD}$	V
	$V_{IL4}$	P60, P61	0		$0.3V_{DD}$	V
	$V_{IL5}$	P121, P122, P125 <sup>Note 1</sup> , P137, EXCLK, RESET	0		$0.2V_{DD}$	V
Output voltage, high	$V_{OH1}$	20-, 24-pin products: P00 to P03 <sup>Note 2</sup> , P10 to P14, P40 to P42 30-pin products: P00, P01, P10 to P17, P30, P31, P40, P50, P51, P120, P147	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OH1} = -3.0\text{ mA}$	$V_{DD}-0.7$		V
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OH1} = -2.0\text{ mA}$	$V_{DD}-0.6$		V
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $I_{OH1} = -1.5\text{ mA}$	$V_{DD}-0.5$		V
	$V_{OH2}$	P20 to P23	$I_{OH2} = -100\text{ }\mu\text{A}$	$V_{DD}-0.5$		V

**Notes** 1. 20, 24-pin products only.

2. 24-pin products only.

**Caution** The maximum value of  $V_{IH}$  of pins P10 to P12 and P41 for 20-pin products, P01, P10 to P12, and P41 for 24-pin products, and P00, P10 to P15, P17, and P50 for 30-pin products is  $V_{DD}$  even in N-ch open-drain mode. High level is not output in the N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## (1) 20-, 24-pin products

 $(T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V})$ 

(2/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit	
Supply current <sup>Note 1</sup>	I <sub>DD2</sub> <sup>Note 2</sup>	HALT mode	HS (High-speed main) mode <sup>Note 6</sup>	f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		440	2230	μA	
					V <sub>DD</sub> = 3.0 V		440	2230		
				f <sub>IH</sub> = 16 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		400	1650	μA	
					V <sub>DD</sub> = 3.0 V		400	1650		
				f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		280	1900	μA	
					Resonator connection		450	2000		
				f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		280	1900	μA	
					Resonator connection		450	2000		
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		190	1010	μA	
					Resonator connection		260	1090		
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		190	1010	μA	
					Resonator connection		260	1090		
	I <sub>DD3</sub> <sup>Note 5</sup>	STOP mode	T <sub>A</sub> = −40°C					0.19	0.50	μA
			T <sub>A</sub> = +25°C					0.24	0.50	
T <sub>A</sub> = +50°C					0.32	0.80				
T <sub>A</sub> = +70°C					0.48	1.20				
T <sub>A</sub> = +85°C					0.74	2.20				
T <sub>A</sub> = +105°C					1.50	10.20				

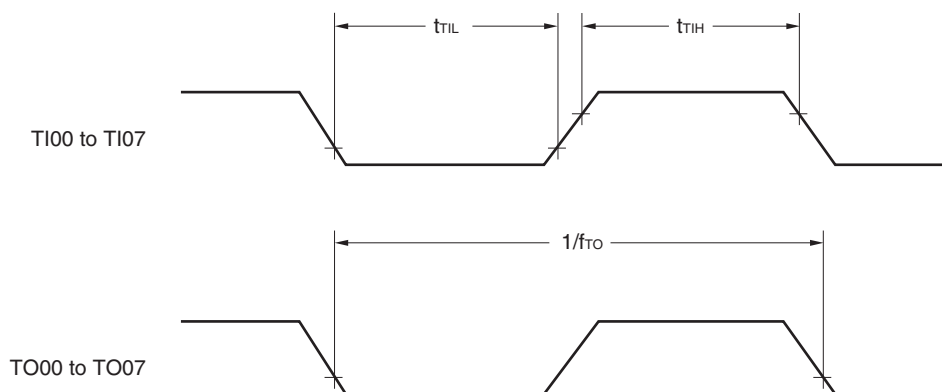
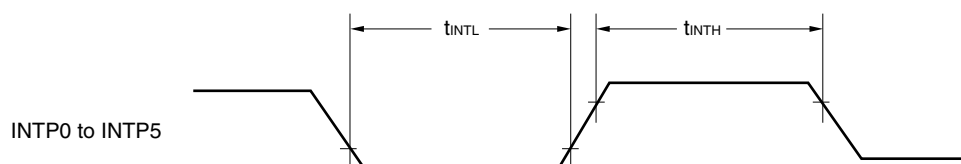
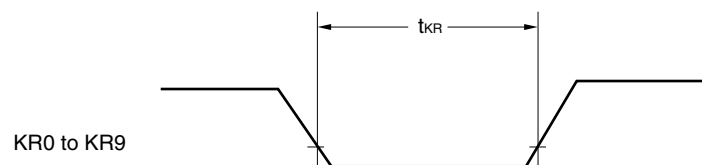
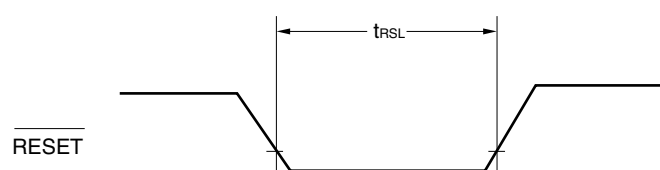
- Notes**
1. Total current flowing into  $V_{DD}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$  or  $V_{SS}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator clock is stopped.
  4. When high-speed system clock is stopped.
  5. Not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Relationship between operation voltage width, operation frequency of CPU and operation mode is as follows.

HS (High speed main) mode:  $V_{DD} = 2.7\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $24\text{ MHz}$

$V_{DD} = 2.4\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $16\text{ MHz}$

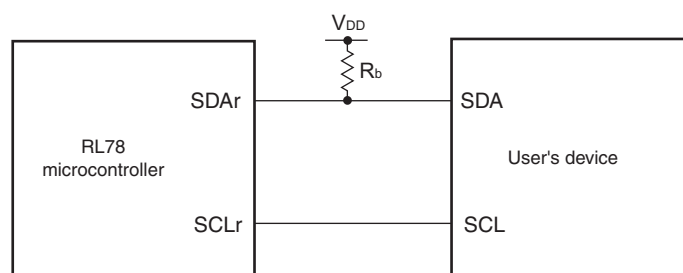
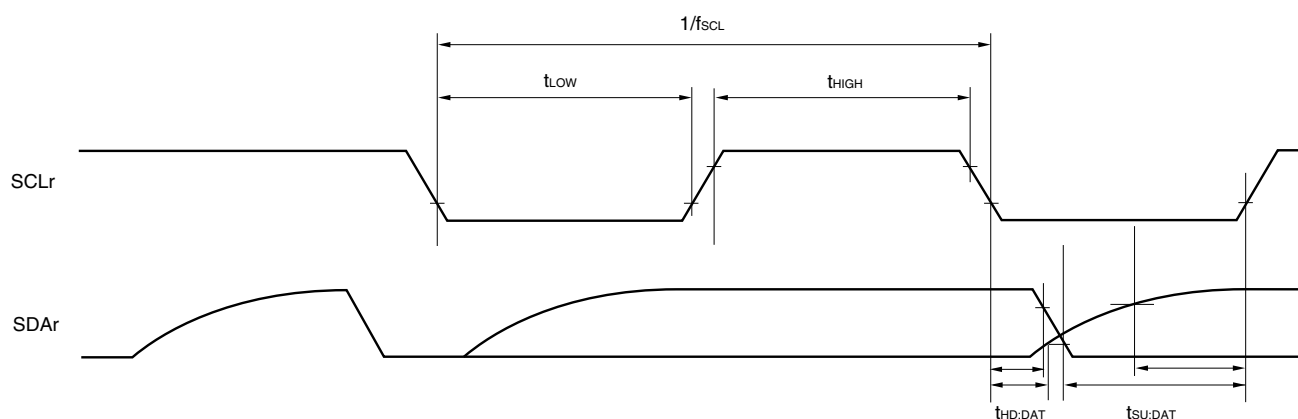
- Remarks**
1.  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2.  $f_{IH}$ : high-speed on-chip oscillator clock frequency
  3. Except temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$ , other than STOP mode



**TI/TO Timing****Interrupt Request Input Timing****Key Interrupt Input Timing****RESET Input Timing**

**(4) During communication at same potential (simplified I<sup>2</sup>C mode)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCLr clock frequency	$f_{\text{SCL}}$	$C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$		100 <sup>Note 1</sup>	kHz
Hold time when SCLr = "L"	$t_{\text{LOW}}$	$C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	4600		ns
Hold time when SCLr = "H"	$t_{\text{HIGH}}$	$C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	4600		ns
Data setup time (reception)	$t_{\text{SU:DAT}}$	$C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	$1/f_{\text{MCK}} + 580$ <sup>Note 2</sup>		ns
Data hold time (transmission)	$t_{\text{HD:DAT}}$	$C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	0	1420	ns

**Notes 1.** The value must also be equal to or less than  $f_{\text{MCK}}/4$ .**2.** Set  $t_{\text{SU:DAT}}$  so that it will not exceed the hold time when SCLr = "L" or SCLr = "H".**Caution** Select the N-ch open drain output ( $V_{DD}$  tolerance) mode for SDAr by using port output mode register h (POMh).**Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)****Remarks 1.**  $R_b$  [ $\Omega$ ]: Communication line (SDAr) pull-up resistance $C_b$  [F]: Communication line (SCLr, SDAr) load capacitance**2.** r: IIC number (r = 00, 01, 11, 20), h: = POM number (h = 0, 1, 4, 5)**3.**  $f_{\text{MCK}}$ : Serial array unit operation clock frequency

(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn).

m: Unit number (m = 0, 1), n: Channel number (0, 1, 3))

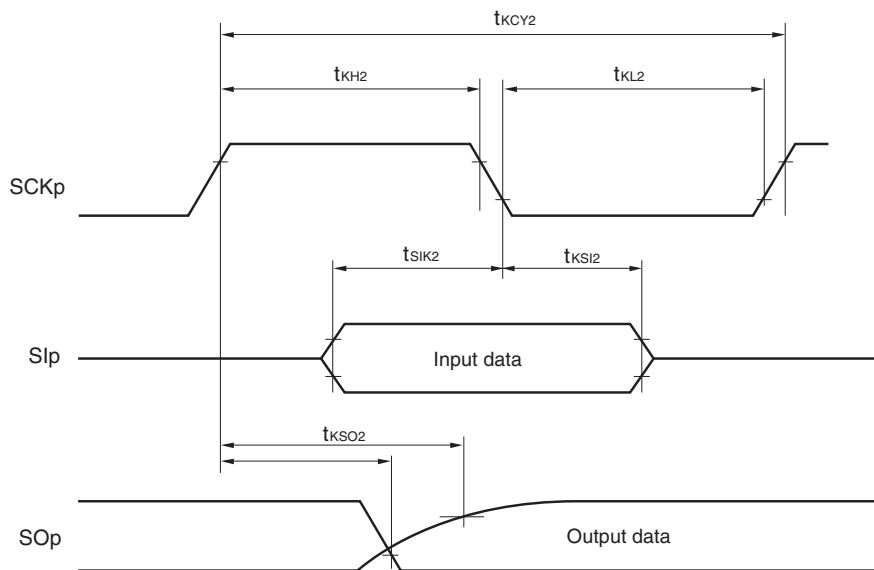
**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (1/3)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		Unit
				MIN.	MAX.	
SCKp cycle time	$t_{KCY1}$	$t_{KCY1} \geq 4/f_{CLK}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	600		ns
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1000		ns
			$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	2300		ns
SCKp high-level width	$t_{KH1}$		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	$t_{KCY1}/2 - 150$		ns
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$t_{KCY1}/2 - 340$		ns
			$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$t_{KCY1}/2 - 916$		ns
SCKp low-level width	$t_{KL1}$		$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	$t_{KCY1}/2 - 24$		ns
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$t_{KCY1}/2 - 36$		ns
			$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$t_{KCY1}/2 - 100$		ns

- Cautions**
1. Select the TTL input buffer for the SIp pin and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SOp pin and SCKp pin by using port input mode register 1 (PIM1) and port output mode register 1 (POM1). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.
  2. CSI01 and CSI11 cannot communicate at different potential.

- Remarks**
1.  $R_b$  [ $\Omega$ ]: Communication line (SCKp, SOp) pull-up resistance,  $C_b$  [F]: Communication line (SCKp, SOp) load capacitance,  $V_b$  [V]: Communication line voltage
  2. p: CSI number (p = 00, 20)

**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark** p: CSI number (p = 00, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0)

(4) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (–) =  $AV_{REFM}$  (ADREFM = 1), target pin: ANI0, ANI2, ANI3, and ANI16 to ANI22

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , Reference voltage (+) =  $V_{BGR}$ <sup>Note 3</sup>, Reference voltage (–) =  $AV_{REFM}$   
<sup>Note 4</sup> = 0 V, HS (high-speed main) mode)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8			bit
Conversion time	$t_{CONV}$	8-bit resolution	17		39	$\mu\text{s}$
Zero-scale error <sup>Notes 1, 2</sup>	EZS	8-bit resolution			$\pm 0.60$	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	8-bit resolution			$\pm 2.0$	LSB
Differential linearity error <sup>Note 1</sup>	DLE	8-bit resolution			$\pm 1.0$	LSB
Analog input voltage	$V_{AIN}$		0		$V_{BGR}$ <sup>Note 3</sup>	V

**Notes** 1. Excludes quantization error ( $\pm 1/2$  LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. Refer to **29.6.2 Temperature sensor/internal reference voltage characteristics**.

4. When reference voltage (–) =  $V_{SS}$ , the MAX. values are as follows.

Zero-scale error: Add  $\pm 0.35\%$ FSR to the MAX. value when reference voltage (–) =  $AV_{REFM}$ .

Integral linearity error: Add  $\pm 0.5$  LSB to the MAX. value when reference voltage (–) =  $AV_{REFM}$ .

Differential linearity error: Add  $\pm 0.2$  LSB to the MAX. value when reference voltage (–) =  $AV_{REFM}$ .